

**Experiment title:**X-Ray Structure Analysis of the EuS/Bi₂Se₃ Interface**Experiment number:**

HC-3820

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Report:

It was the aim of the experiment to carry out SXRD experiments to study the atomic structure of the EuS/Bi₂Se₃(0001) interface. The experiments could be carried out very successfully, and the data analysis still in progress. In detail: The (0001) surface of a

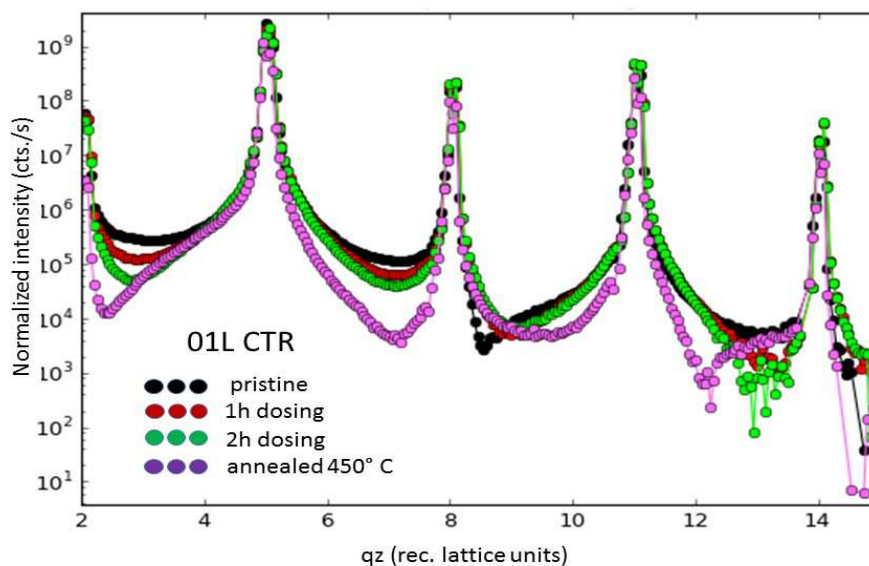


Fig.1 Comparison of intensities collected for clean and EuS covered Bi₂Se₃(0001) along the (01L) CTR.

bulk single Bi_2Se_3 crystal was first prepared by sputtering and annealing as done previously [1,2]. The intensity distribution along several symmetry independent crystal truncation rods (CTRs) was collected for the pristine surface first.

In the next step, EuS was deposited in the ultra-thin film thickness range using a Knudsen cell loaded with EuS powder. This takes about 2 hours at a temperature of 840°C . According to our in-house experiments (see STM image below) this leads to a film thickness of about 1 unit cell along the (111) direction of cubic EuS ($a_0=5.97 \text{ \AA}$)

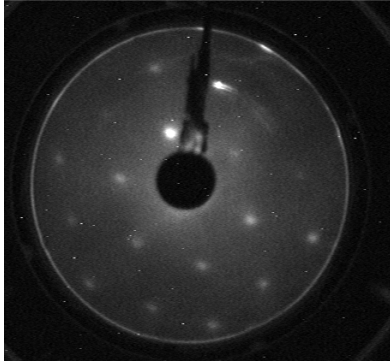


Fig.2: LEED ($E_{\text{kin}}=123\text{eV}$) pattern after EuS deposition on $\text{Bi}_2\text{Se}_3(0001)$. Only (1x1) spots related to the substrate are observed according to the good lattice matching of EuS to Bi_2Se_3 (4.22 vs. 4.14 \AA).

which is equal to 10.34 \AA . Fig. 1 shows for comparison the (01L) CTR collected for the clean and EuS covered Bi_2Se_3 (0001) surface, respectively. It can be seen that there is a substantial modification of the CTRs related to adsorption of EuS. LEED investigations (see Fig.2) has shown that there is only a (1x1) pattern present and no

superstructure forms.

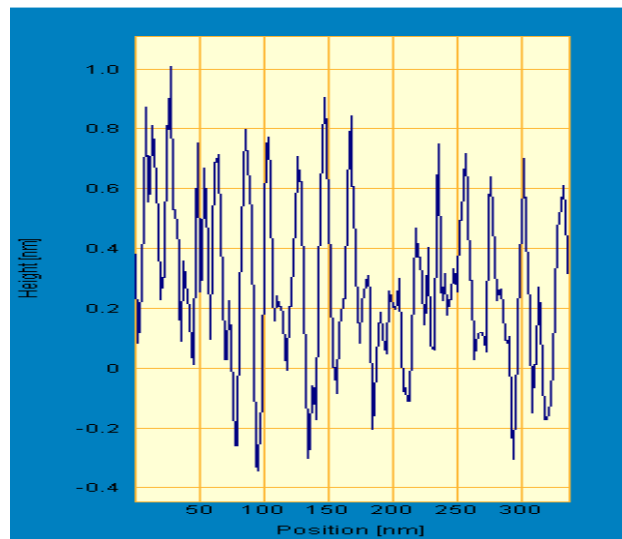
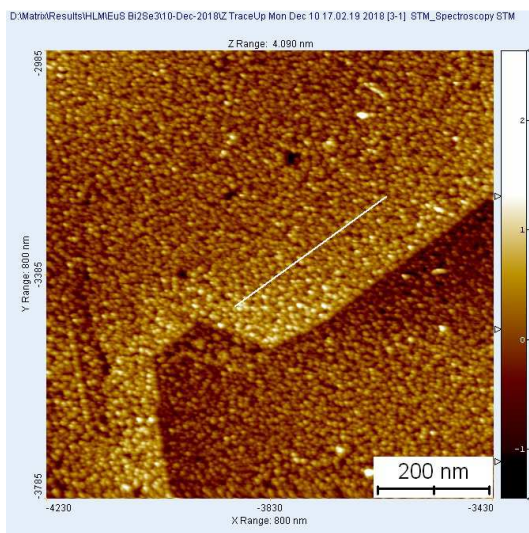


Fig.3: (left) STM image ($U=1 \text{ V}$, $I=500 \text{ nA}$) taken from the in-house experiment closely related to the SXRD experiments showing a fully EuS covered $\text{Bi}_2\text{Se}_3(0001)$ surface, in which two substrate terraces are separated by a step. (Right side): The profile along the white line indicates an apparent maximum height of the EuS islands of about 1 nm related to one unit cell along the [111] direction of cubic EuS.

Until now, no completely satisfying fit of the CTR intensities is available which would allow a clear-cut statement of the film and interface structure. Preliminary analysis suggests however, that there is substantial atomic intermixing across the EuS/ Bi_2Se_3 interface. This observation might be important to understand the recently observed unusual magnetic properties [3]. The data analysis is still in progress.

References:

- [1] Sumalay Roy, H. L. Meyerheim, A. Ernst et al., *Phys. Rev. Lett.* 113, 116802 (2014)
- [2] H. L. Meyerheim and C. Tusche, *Physica Status Solidi RRL*, 1800078 (2018)
- [3] F. Katmis, V. Lauter, F. S. Noguera, et al., *Nature* 533, 513 (2016)